





## 150mA Low Noise CMOS LDO

#### **SOT-343**

## 01-343

# 4 3 1 2

#### Pin Definition:

- 1. Enable
- 2. Ground
- Output
   Input

## SOT-25



#### Pin Definition:

- 1. Input
- 2. Ground
- 3. Enable
- 4. Bypass
- 5. Output

#### DFN 2x2

## Pin Definition:

- 1. Input
- 2. N/C
- 3. Output
- 4. N/C
- 5. Ground
- 6. Enable

#### **General Description**

TS9006 series is 150mA low-noise CMOS LDO especially designed for battery-power RF and wireless applications. The TS9006 regulator achieves a low 250mV dropout at 150mA load current of 3.3V output, ultra-low output voltage noise of 15uVrms and PSRR of 57dB at 1KHz.TS9006 regulators are also optimized to work with low-ESR and low cost ceramic capacitors reducing the amount of board space critical in hand-held devices. The TS9006 requires only 0.47uF output capacitor for stability with and load. The TS9006 consumes less than 1uA in shutdown mode.

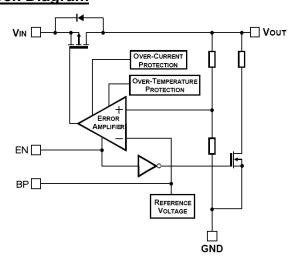
#### **Features**

- 250mV Dropout at 150mA load (3.3V)
- Quiescent current: 90μA (typ.)
- Output voltage ±2%
- Internal current limit and thermal shutdown
- Power saving shutdown mode (<1uA)</li>
- Only need input and output capacitors
- Build-In internal Soft-Start
- Output short-circuit current limit protection

#### **Applications**

- Palmtops, PDA and Notebook Computers
- DSC, Handset Camera Modules
- PCMCIA Cards, PC Cameras
- USB Based Portable Devices (MPS, PMP)
- GSM/GPRS/3G RF Transceiver Modules

### **Block Diagram**



#### **Ordering Information**

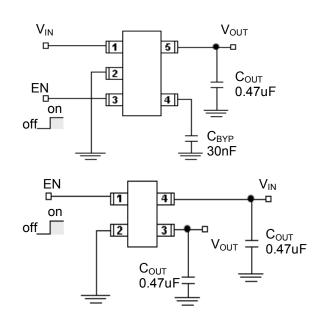
Part No.	Package	Packing
TS9006 <u>x</u> CX5 RF	SOT-25	3Kpcs / 7" Reel
TS9006 <u>x</u> CU4 RF	SOT-343	3Kpcs / 7" Reel
TS9006 <u>x</u> CQ6 RF	DFN 2x2	3Kpcs / 7" Reel

Note: Where **x** denotes voltage option, available are **D**= 1.8, **K**= 2.5V, **M**= 2.7V, **N**= 2.8V, **P**= 3.0V,

**S**= 3.3V

Contact factory for additional voltage options.

## **Typical Application Circuit**



EN (Pin 3) may be connected directly to  $V_{IN}$  (Pin1) Low noise operation:  $C_{BYP}$ =30nF,  $C_{OUT}$ >0.47uF Basic operation:  $C_{BYP}$ =not used,  $C_{OUT}$ >1uF





## 150mA Low Noise CMOS LDO

**Absolute Maximum Rating** 

Parameter		Symbol	Limit	Unit
Supply Voltage		V <sub>IN</sub>	-0.3 ~ +7	V
Input Supply Voltage (Recommended)		$V_{OPR}$	+2 ~ +6	V
Output Short-Circuit Duration			Infinite	
	SOT-25	P <sub>D</sub>	300	
Power Dissipation	SOT-343		200	mW
	DFN 2x2		500	
	SOT-25		250	
Thermal Resistance	SOT-343	$\Theta_{JA}$	333	°C/W
	DFN 2x2		165	
Junction Temperature Range		T <sub>J</sub>	+150	°C
Storage Temperature Range		T <sub>STG</sub>	-65 ~ +150	°C

Notes: Stress above the listed absolute rating may cause permanent damage to the device.

 $\textbf{Electrical Characteristics} \text{ (Ta=25°C, V}_{IN} = \text{ (Vout+1V), C}_{IN} = \text{C}_{OUT} = \underline{0.47} \text{uF, V}_{EN} = \text{V}_{IN}, \text{ unless otherwise noted.)}$ 

Parameter	Conditions	Min	Тур	Max	Unit	
Output Voltage	V <sub>IN</sub> =Vo + 1V, IO=10mA	-2.0		+2	%	
Output Current Limit	Short-circuit output		200		mA	
Line Regulation	$V_{IN} = (V_{OUT} + 1V)$ to 6V, $I_{O} = 10$ mA		0.3		%/V	
Load Regulation	I <sub>OUT</sub> =1mA to 150mA		0.2	1.0	%	
	V <sub>OUT</sub> =3.3V, I <sub>OUT</sub> =150mA		250			
	V <sub>OUT</sub> =3.0V, I <sub>OUT</sub> =150mA		275			
Dronout Voltage	V <sub>OUT</sub> =2.8V, I <sub>OUT</sub> =150mA		300		m\/	
Dropout Voltage	V <sub>OUT</sub> =2.7V, I <sub>OUT</sub> =150mA		310		mV	
	V <sub>OUT</sub> =2.5V, I <sub>OUT</sub> =150mA		320			
	V <sub>OUT</sub> =1.8V, I <sub>OUT</sub> =150mA		500			
Shutdown Supply Current	EN=0V		0.01		uA	
Ground Pin Current	lo=0mA		90		uA	
	f=100Hz, lo=1mA		52			
Ripple Rejection (PSRR)	f=1KHz, lo=1mA		55		dB	
	f=10Hz, Io=1mA		53			
Output Noise	Io=10mA, f=10Hz to 100kHz, Bypass = 0nF		45		uVrms	
Output Noise	lo=10mA, f=10Hz to 100kHz, Bypass = 30nF		15			
Shutdown Exit Delay (note 2)	RLOAD = $50\Omega$		45	300	uS	
EN Logic Low Level	V <sub>IN</sub> =2.0V to 5.5V			0.4	V	
EN Logic High Level	V <sub>IN</sub> =2.0V to 5.5V	1.5		VIN		
EN Input Bias Current	V <sub>IN</sub> =5.5V, EN=0V or 6V		0.01		uA	
Thermal Shutdown	Shutdown Temperature		160		°C	
Thermal Shutdown Hysteresis			20		°C	

#### Notes:

b. Time needed for  $V_{\text{OUT}}$  to reach 90% of final value

a. The drop out voltage varies depending on output voltage selection Dropout is defined as  $V_{IN}$  -  $V_{OUT}$  when  $V_{OUT}$  is 100mV below  $V_{OUT}$  where  $V_{IN}$  =  $V_{OUT}$  +1V for nominal  $V_{OUT}$ 

# TS9006 150mA Low Noise CMOS LDO



#### **Application Information**

#### **Enable / Shutdown**

The TS9006 comes with and active-high enable pin that allows the regulator to be enabled. Forcing the enable pin low disables the regulator and puts it into the shutdown mode. This pin cannot be left floating as it may cause an undetermined state.

#### **Input / Output Capacitor**

It is recommended to use a 0.47uF capacitor on the TS9006 input and a 0.47uF capacitor on the output. For high regulation performance, larger input capacitor values and lower ESRs provide better noise rejection and line-transient response. The output noise, load-transient response, stability, and power-supply rejection can be improved by using large output capacitors. Low ESR ceramic capacitors provide optimal performance and save space.

#### Power Supply Rejection and Transient Response

The PSRR and transient response can be improved by increasing the values of the input and output bypass capacitors, and through passive filtering techniques

#### **Functional Description**

#### **Description**

The TS9006 is an ultra-low-noise, low-quiescent current, low-dropout linear regulator. It is supplied in a SOT-25, SOT-343 & DFN 2x2 package for difference applications. This device can supply loads up to 150mA. As shown in the functional block diagram, the TS9006 consists of a reference and noise bypass circuit, error amplifier, output drive transistor, internal feedback voltage divider, thermal sensor, and short circuit current limiter. The internal reference is connected to the error amplifier's inverting input. The error amplifier compares this reference with the feedback voltage and amplifies the difference. If the feedback voltage is lower than the reference voltage, the pass=transistor gate is pulled low. This allows more current to pass to the output and increases the output voltage.

#### **Stability**

The TS9006 is a high performance LDO emphasizing stability with low output capacitance. It is able to maintain stability with an output capacitor can also be increased to optimize performance. The TS9006 will remain stable and in regulation with no load, unlike many other voltage regulators.

#### **Internal P-Channel Pass Transistor**

The TS9006 features allow impedance P-channel MOSFET pass transistor. This provides several advantages over similar designs using a PNP pass transistor, including low operating power and longer battery life. The TS9006 consumes only  $90\mu A$  of quiescent current under most conditions.

#### **Output Short-Circuit Current Limit**

The TS9006 includes a current limiter, which monitors and controls the pass transistor's gage voltage, limiting the output current to about 200mA, for example, in a short-circuit output situation.

#### Shutdown

The TS9006 also features a low-power active shutdown mode. It has a switch that turns off the device when disabled. This allows the output capacitor and load to discharge and de-energize the load. In the shutdown mode, the internal functional blocks, such as voltage reference and the error amplifier, are turned off completely, and the quiescent current is less than  $1\mu A$ .



# Pb RoHS

# TS9006 150mA Low Noise CMOS LDO

## **Functional Description (Continue)**

#### **Thermal Protection Shutdown**

The thermal protection shutdown function protects the device from operating in over temperature condition. When the junction temperature exceeds  $+160^{\circ}$ C, the thermal sensor signals the shutdown logic, turning off the pass transistor and allowing the IC to tool down. The thermal sensor turns the pass transistor on again after the IC's junction temperature drops to  $+140^{\circ}$ C.

#### **Soft-Start Circuitry**

The TS9006 includes a soft-start circuitry to limit inrush current at turn-on. During power up, the output capacitor and output load are charged with a reduce output current. Shortly after the initial power up, the soft-start feature is terminated and normal operation is resumed.

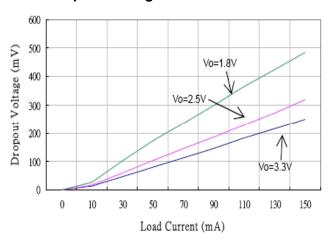




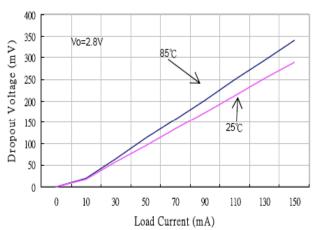
## 150mA Low Noise CMOS LDO

#### **Electrical Characteristics Curve**

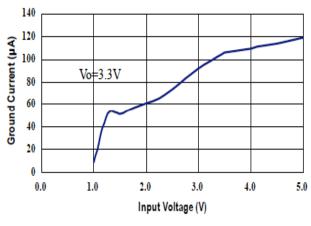
#### **Dropout Voltage vs. Load Current**



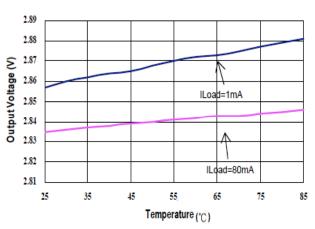
# **Dropout Voltage vs. Temperature**



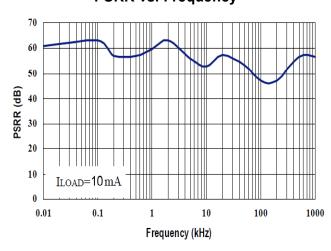
#### **Ground Current vs. Input Voltage**



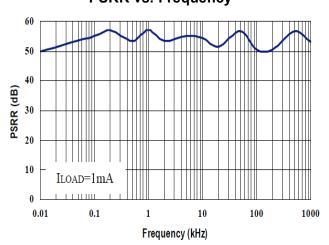
Output Voltage vs. Temperature



#### **PSRR vs. Frequency**



**PSRR vs. Frequency** 

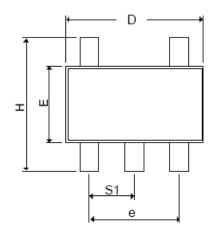






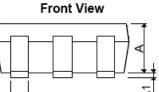


# **SOT-25 Mechanical Drawing**

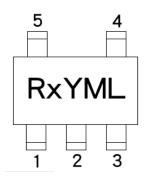




SOT-25 DIMENSION					
DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX.	
A+A1	0.09	1.25	0.0354	0.0492	
В	0.30	0.50	0.0118	0.0197	
С	0.09	0.25	0.0035	0.0098	
D	2.70	3.10	0.1063	0.1220	
Е	1.40	1.80	0.0551	0.0709	
Е	1.90 BSC		0.0748	B BSC	
Н	2.40	3.00	0.09449	0.1181	
L	0.35 BSC		0.0138	B BSC	
θ1	0°	10°	0°	10°	
S1	0.95 BSC		S1 0.95 BSC 0.037		4 BSC



# **Marking Diagram**



A = Device Code

X = Fixed Output Voltage Code
 D=1.8V, K=2.5V, M=2.7V, N=2.8V, P=3.0V, S=3.3V

Y = Year Code

M = Month Code

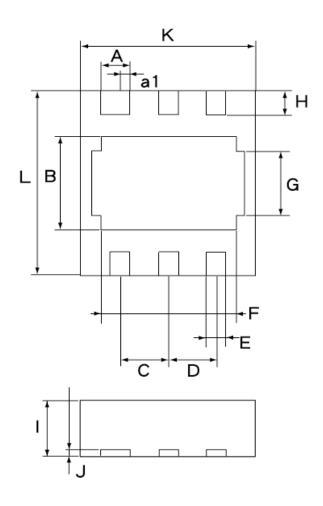
(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)

**L** = Lot Code



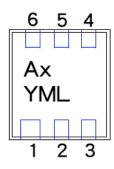


# **DFN 2x2 Mechanical Drawing**



DFN 2x2 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
Α	0.25	0.35	0.0098	0.0138
a1	0.10 (typ)		0.10 (typ) 0.0039 (typ)	
В	0.90	1.10	0.0354	0.0433
С	0.50 (typ)		0.0197 (typ)	
D	0.50 (typ)		0.0197 (typ)	
E	0.15	0.25	0.0059	0.0098
F	1.30	1.50	0.0512	0.0591
G	0.67	0.73	0.0264	0.0287
Н	0.20	0.30	0.0079	0.0118
1	0.60 (MAX.)		0.0236	(MAX.)
J	0.07 (MAX.)		0.0028 (MAX.)	
K	1.75	1.85	0.0689	0.0728
Ĺ	1.95	2.05	0.0768	0.0807

# **Marking Diagram**



A = Device Code

X = Fixed Output Voltage Code

**D**=1.8V, **K**=2.5V, **M**=2.7V, **N**=2.8V, **P**=3.0V, **S**=3.3V

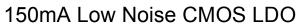
Y = Year Code

**M** = Month Code

(A=Jan, B=Feb, C=Mar, D=ApI, E=May, F=Jun, G=Jul, H=Aug,

I=Sep, J=Oct, K=Nov, L=Dec)

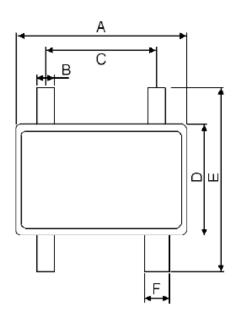
**L** = Lot Code

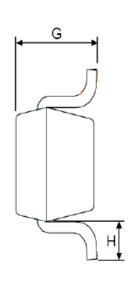






# **SOT-343 Mechanical Drawing**





SOT-343 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
Α	1.80	2.20	0.0709	0.0866
В	0.25	0.40	0.0098	0.0157
С	1.30(typ)		0.0512(typ)	
D	1.15	1.35	0.0453	0.0531
Е	1.80	2.40	0.0709	0.0945
F	0.35	0.50	0.0137	0.0197
G	0.80	1.10	0.0315	0.0433
Η	0.10	0.45	0.0039	0.0177



# TS9006 150mA Low Noise CMOS LDO

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